



MBR10H100CT - MBR10H200CT

10.0 AMPS. Schottky Barrier Rectifiers

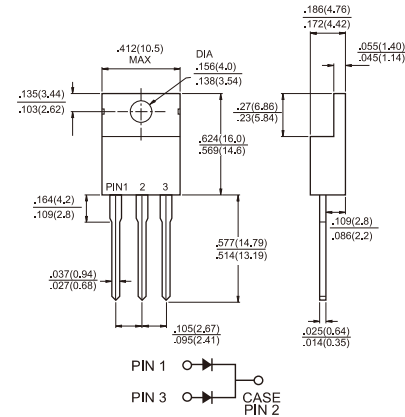
TO-220AB

Features

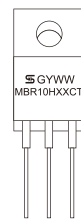
- ◇ UL Recognized File # E-326243
- ◇ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ◇ Metal silicon junction, majority carrier conduction
- ◇ Low power loss, high efficiency
- ◇ High current capability, low forward voltage drop
- ◇ High surge capability
- ◇ For use in power supply – output rectification, power management, instrumentation
- ◇ Guardring for overvoltage protection
- ◇ High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case
- ◇ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ◇ Cases: JEDEC TO-220AB molded plastic body
- ◇ Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Mounting position: Any
- ◇ Mounting torque: 5 in. - lbs. max
- ◇ Weight: 1.88grams



Dimensions in inches and (millimeters)



Marking Diagram

MBR10HXXCT = Specific Device Code
G = Green Compound
Y = Year
WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBR 10H100CT	MBR 10H150CT	MBR 10H200CT	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	100	150	200	V
Maximum RMS Voltage	V _{RMS}	70	105	140	V
Maximum DC Blocking Voltage	V _{DC}	100	150	200	V
Maximum Average Forward Rectified Current at Tc=125°C	I _{F(AV)}	10			A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=125°C	I _{FRM}	10			A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	120			A
Peak Repetitive Reverse Surge Current (Note 2)	I _{RRM}	1.0		0.5	A
Maximum Instantaneous Forward Voltage at: I _F =5A, T _A =25°C I _F =5A, T _A =125°C I _F =10A, T _A =25°C I _F =10A, T _A =125°C	V _F	0.85 0.75 0.95 0.85	0.88 0.75 0.97 0.85		V
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @ T _A =25 °C @ T _A =125 °C (Note 1)	I _R	5 1.0			uA mA
Voltage Rate of Change (Rated V _R)	dV/dt	10,000			V/uS
Maximum Typical Thermal Resistance (Note 3)	R _{θJc}	1.5			°C/W
Operating Junction Temperature Range	T _J	-65 to +175			°C
Storage Temperature Range	T _{STG}	-65 to +175			°C

- Notes: 1. Pulse Test: 300us Pulse Width, 1% Duty Cycle
2. 2.0us Pulse Width, f=1.0 KHz
3. Mount on Heatsink Size of 2 in x 3 in x 0.25in Al-Plate.

Version: E10

RATINGS AND CHARACTERISTIC CURVES (MBR10H100CT THRU MBR10H200CT)

FIG.1- FORWARD CURRENT DERATING CURVE

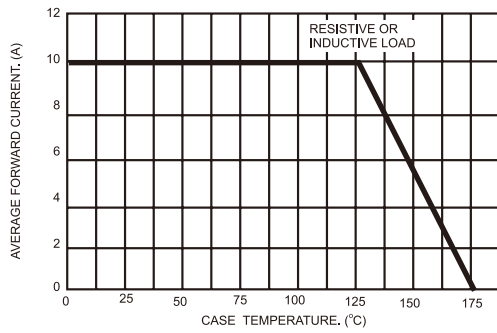


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

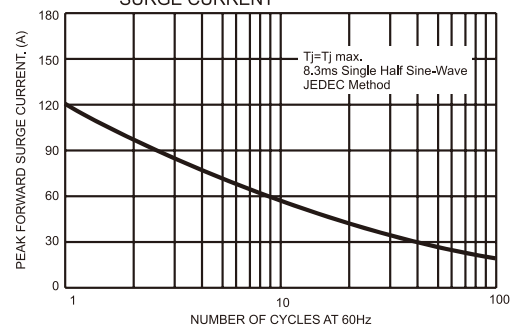


FIG.3- TYPICAL FORWARD CHARACTERISTICS

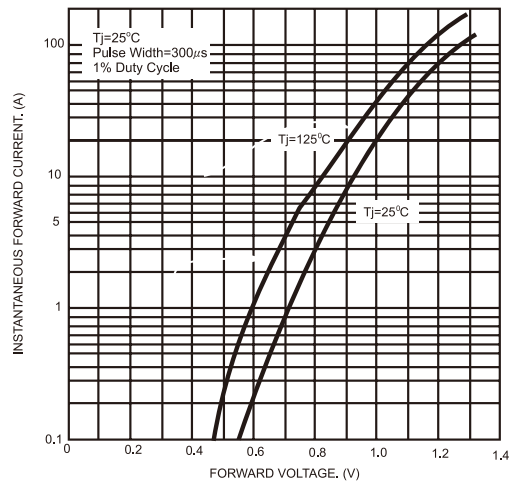


FIG.4- TYPICAL REVERSE CHARACTERISTICS

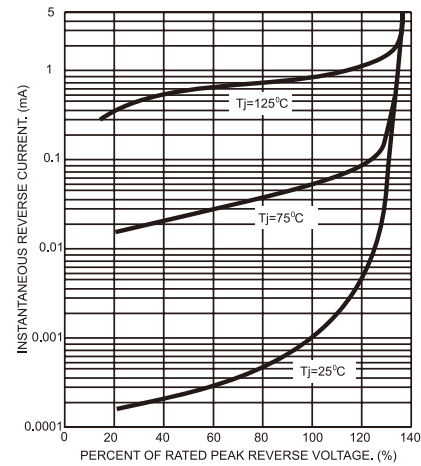


FIG.5- TYPICAL JUNCTION CAPACITANCE

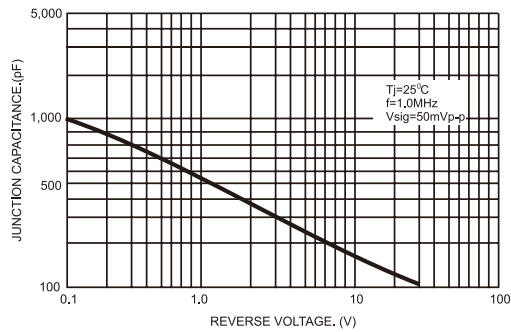


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS PER LEG

